



DMG6898LSD

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C | | |
|-------------------|-----------------------------|--|--|--|
| 20V | $16m\Omega @ V_{GS} = 4.5V$ | 9.8A | | |
| | $23m\Omega @ V_{GS} = 2.5V$ | 8.7A | | |

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Backlighting
- Power management functions
- DC-DC converters

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected up to 2kV
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMG6898LSDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

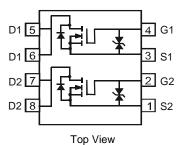
Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish- Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: 0.072 grams (Approximate)





Top View



Internal Schematic

Ordering Information (Note 4)

| Part Number | Qualification | Package | Packing | | |
|----------------|---------------|---------|---------|-------------|--|
| | | Fackage | Qty. | Carrier | |
| DMG6898LSD-13 | Commercial | SO-8 | 2,500 | Tape & Reel | |
| DMG6898LSDQ-13 | Automotive | SO-8 | 2,500 | Tape & Reel | |

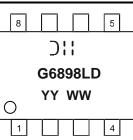
No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Char | Symbol | Value | Unit | | |
|-----------------------------------|-----------------|--|------------------|------------|---|
| Drain-Source Voltage | | | Vdss | 20 | V |
| Gate-Source Voltage | | | V _{GSS} | ±12 | V |
| Continuous Drain Current (Note 5) | Steady State | T _A = +25°C T _A = +85°C | ID | 9.5 7.1 | А |
| Pulsed Drain Current (Note 6) | ldм | 30 | А | | |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|----------|-------------|------|
| Power Dissipation (Note 5) | PD | 1.28 | W |
| Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5) | Reja | 99.3 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | ٦° |

Electrical Characteristics @TA = +25°C unless otherwise specified

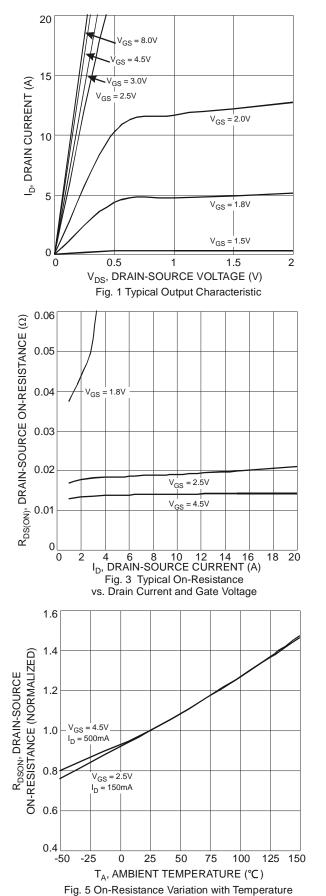
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|-----------------------------|-----|-------|-----|------|--|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 20 | | | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current T _J = +25°C | IDSS | | | 1.0 | μA | $V_{DS} = 20V, V_{GS} = 0V$ | |
| Gate-Source Leakage | lgss | | _ | ±10 | μA | $V_{GS} = \pm 12V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | VGS(TH) | 0.5 | 1.0 | 1.5 | V | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | RDS(ON) | | 11 | 16 | mΩ | $V_{GS} = 4.5V, I_D = 9.4A$ | |
| Static Drain-Source Off-Resistance | | _ | 17 | 23 | | VGS = 2.5V, ID = 8.3A | |
| Forward Transfer Admittance | Yfs | | 17 | | s | $V_{DS} = 5V, I_{D} = 9.4A$ | |
| Diode Forward Voltage | Vsd | | 0.7 | 1.2 | V | $V_{GS} = 0V, I_{S} = 1.3A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | Ciss | | 1149 | | pF | | |
| Output Capacitance | Coss | | 157 | | pF | Vps = 10V, Vgs = 0V, f = 1.0MHz | |
| Reverse Transfer Capacitance | Crss | | 142 | | pF | 1 = 1.000112 | |
| Gate Resistance | Rg | _ | 1.51 | _ | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 11.6 | _ | nC | V _{DS} = 10V, I _D = 9.4A | |
| Total Gate Charge (V _{GS} = 10V) | Qg | — | 26 | — | nC | | |
| Gate-Source Charge | Qgs | | 2.7 | | nC | | |
| Gate-Drain Charge | Q _{gd} | — | 3.4 | — | nC | | |
| Turn-On Delay Time | t _{D(ON)} | | 11.67 | | ns | | |
| Turn-On Rise Time | tr | _ | 12.49 | _ | ns | V _{DD} = 10V, V _{GS} = 4.5V, | |
| Turn-Off Delay Time | tD(OFF) | | 35.89 | | ns | $R_{GEN} = 6\Omega, I_D = 1A$ | |
| Turn-Off Fall Time | tf | | 12.33 | | ns |] | |

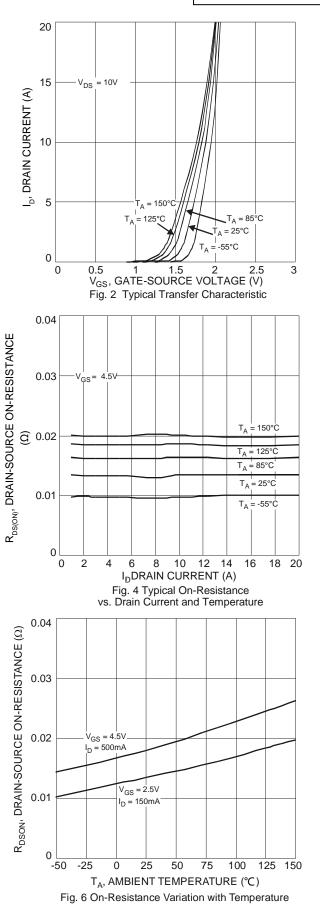
5. Device mounted on FR-4 PCB, with minimum recommended pad layout. Notes:

Repetitive rating, pulse width limited by junction temperature.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.



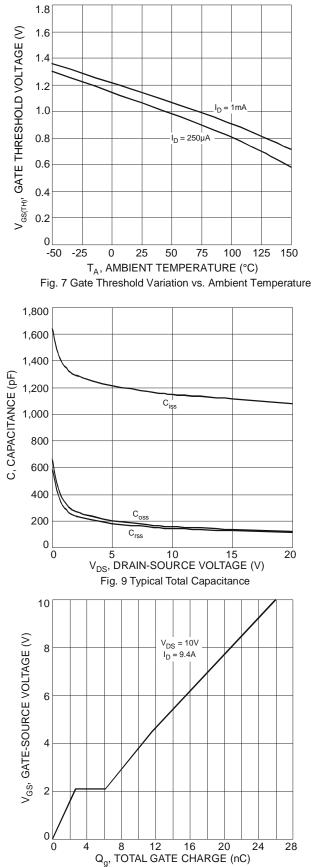
DMG6898LSD



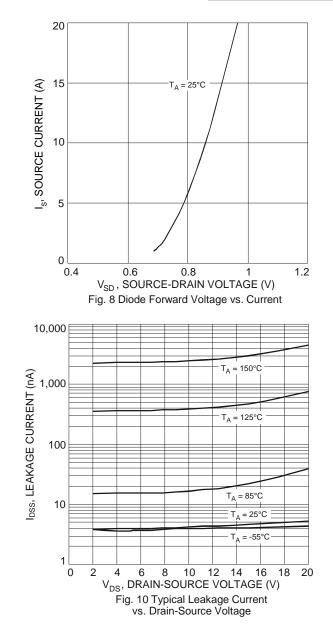




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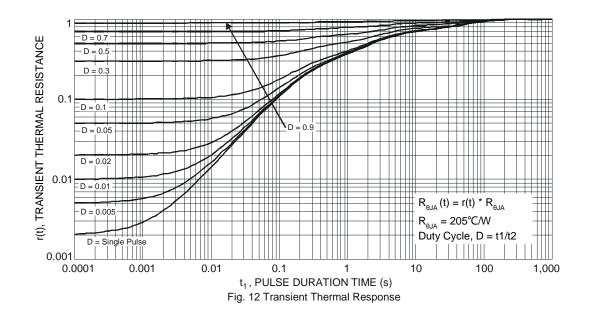








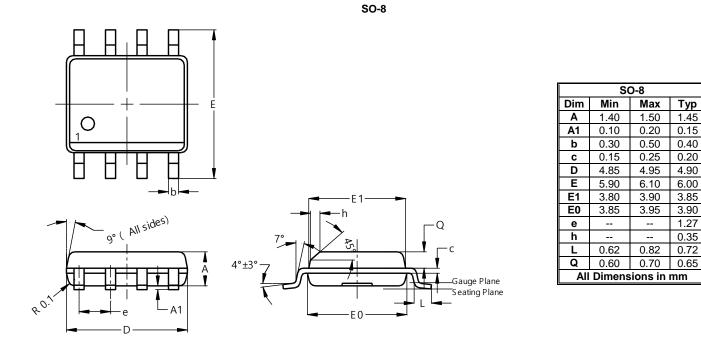






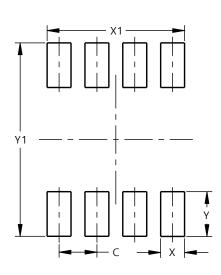
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



| Dimensions | Value (in mm) | | | |
|------------|---------------|--|--|--|
| С | 1.27 | | | |
| Х | 0.802 | | | |
| X1 | 4.612 | | | |
| Y | 1.505 | | | |
| Y1 | 6.50 | | | |

SO-8



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